

# **Advance Information**

February 1996

### DESCRIPTION

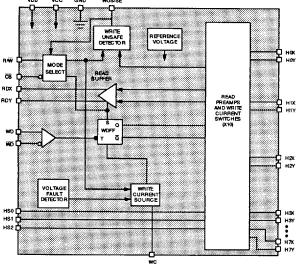
The SSI 32R2103R/04R/05R are BiCMOS monolithic integrated circuits designed for use with two-terminal recording heads. They provide a low noise read amplifier, a high performance write driver, write current control, and data protection circuitry for up to 10 channels. The SSI32R2103R/04R/05R option provides internal 250Ω damping resistors. Damping resistors are switched in during write mode and switched out during read mode. The SSI 32R2103/04/05 option does not provide damping resistors. Power supply fault protection is provided by disabling the write current generator during power sequencing. System write to read recovery time is significantly improved by making the read channel outputs high impedance. The device also offers multiple channel "servo bank write" capability to assist in servo writing operations.

The SSI 32R2103R/04R/05R requires 5V and 12V power supplies. The SSI 32R2103R/2105R provides PECL write data input with flip-flop. The SSI 32R2104R provides PECL direct write data input without flip-flop.

#### **FEATURES**

- 5V ±10%, 12V ±10% supply
- Low power
  - PD = 235 mW read mode (Nom)
  - PD = 12 mW idle (Max)
- High Performance:
  - Read mode gain = 250 V/V
  - Input noise = 0.45 nV/√Hz (Nom)
  - Input capacitance = 10 pF (Nom)
  - Write current range = 10-35 mA
  - Max write current rise/fail time = 7 ns (typical head)
  - Head voltage swing = 11 Vp-p min
- Servo bank write capability
- Self-switching damping resistance
- · Write unsafe detection
- · Power supply fault protection
- Head short to ground protection
- With write data flip-flop (32R2103R/2105R) or without write data flip-flop (32R2104R)

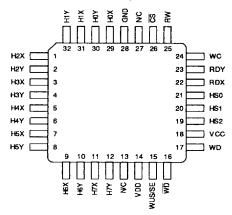
#### 32R2103R BLOCK DIAGRAM



02/16/96 - rev.

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### **PIN DIAGRAM**



SSI 32R2103R 32-Lead, PECL Write Data Input 8-Channel TQFP

> CAUTION: Use handling procedures necessary for a static sensitive component.

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#### **CIRCUIT OPERATION**

The SSI 32R2103R/04R/05R have the ability to address up to 10 two-terminal heads and provide write drive or read amplification. Mode control and head selection are described in Tables 1, 2 and 3. The TTL inputs  $R\overline{W}$ , and  $\overline{CS}$  have internal pull-up circuitry to prevent an accidental write condition. HS0, HS1, HS2 and HS3 have internal pulldown circuitry. Internal current limit circuitry will protect the IC from a head short to ground condition in any write mode.

TABLE 1: Head Select\*

| Head     | 32R | 32R2103R/04R/05R - 10 |     |     |     | 3R/04R | /05R - 8 |
|----------|-----|-----------------------|-----|-----|-----|--------|----------|
| Selected | HS3 | HS2                   | HS1 | HS0 | HS2 | HS1    | HS0      |
| 0        | 0   | 0                     | 0   | 0   | 0   | 0      | 0        |
| 1        | 0   | 0                     | 0   | 1   | 0   | 0      | 1        |
| 2        | 0   | 0                     | 1   | 0   | 0   | 1      | 0        |
| 3        | 0   | 0                     | 1   | 1   | 0   | 1      | 1        |
| 4        | 0   | 1                     | 0   | 0   | 1   | 0      | 0        |
| 5        | 0   | 1                     | 0   | 1   | 1   | 0      | 1        |
| 6        | 0   | 1                     | 1   | 0   | 1   | 1      | 0        |
| 7        | 0   | 1                     | 1   | 1   | 1   | 1      | 1        |
| 8        | 1   | 0                     | 0   | 0   | NA  | NA     | NA       |
| 9        | 1   | 0                     | 0   | 1   | NA  | NA     | NA       |

<sup>\*</sup>Do not use invalid Head Select combinations.

TABLE 2: Mode Select

| CS | R/W | WUS/SE | Mode                               |
|----|-----|--------|------------------------------------|
| 0  | 0   | *      | Single Channel Write. See Table 1. |
| 0  | 0   | **     | Servo/Bank Write. See Table 3.     |
| 0  | 1   | Х      | Single Channel Read. See Table 1.  |
| 1  | Х   | Х      | Idle.                              |

<sup>\*</sup> WUS/SE is a WUS output unless pulled above VCC.

TABLE 3: Servo Write Mode\*

| Head<br>Selected | Head Selected (servo bank write) | HS3 | HS2 | HS1 | HS0 |
|------------------|----------------------------------|-----|-----|-----|-----|
| 0                | no heads selected                | 0   | 0   | 0   | 0   |
| 1                | H0, H1                           | 0   | 0   | 0   | 1   |
| 2                | H2, H3                           | 0   | 0   | 1   | 0   |
| 3                | H0, H1, H2, H3                   | 0   | 0   | 1   | 1   |
| 4                | no heads selected                | 0   | 1   | 0   | 0   |
| 5                | H4, H5                           | 0   | 1   | 0   | 1   |
| 6                | H6, H7,                          | 0   | 1   | 1   | 0   |
| 7                | H4, H5, H6, H7                   | 0   | 1   | 1   | 1   |
| 8                | no heads selected                | 1   | 0   | 0   | 0   |
| 9                | H8, H9                           | 1   | 0   | 0   | 1   |

<sup>\*</sup>Do not use invalid Head Select combinations.

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<sup>\*\*</sup> Servo write mode is activated through the WUS pin as described in the servo write mode section.

#### WRITE MODE

Taking both CS and R/W low selects write mode which configures the SSI 32R2103R/04R/05R as a current switch and activates the Write Unsafe (WUS) detector circuitry. On the 32R2103R/05R, head current is toggled between the X and Y side of the selected head on each low to high transition of WD-WD. Note that a preceding read to write transition or idle to write transition initializes the write data Flip-Flop to pass write current into the "X" side of the device. In this case, the Y side is higher potential than the X side. With the 32R2104R, head current is toggled between the X and Y side of the head on each WEX-WDY transition. When the potential of WDX is higher than WDY, the potential on the X side of the head is higher than the Y-Side (HNY is sinking current). The magnitude of the write current (0-pk) is given by:

 $Iw = Aw \cdot \frac{Vwc}{Rwc} = \frac{K}{Rwc}$ 

where Aw is the write current gain.

RWC is connected from pin WC to GND. Note the actual head current lx, y is given by:

$$lx, y = \frac{lw}{1 + Rh/Rd}$$

where:

Rh = Head resistance plus external wire resistance

Rd = Damping resistance

In write mode a 250 $\Omega$  damping resistor is switched in across the Hx, Hy ports (32R2103R/04R/05R only). Unselected heads are at ground potential.

### **SERVO WRITE MODE**

This mode allows for writing to multiple channels at once, which is useful during servo formatting.

To enable servo write mode follow these steps:

- (1) Place the device in the read mode (R/W high).
- (2) Set the head select lines to an address that corresponds to the bank of heads desired for servo write (See Table 3).

- (3) Pull the WUS/SE output above Vcc by sourcing 10 mA of current into the pin. Two ways to source this current are: (a) use a voltage source set to Vcc +1.9 volts limited to 10 mA current, or (b) use a resistor tied between WUS/SE and a supply above Vcc to source the current. With 10 mA of current, WUS/SE will rise to approximately Vcc + 1.5 volts.
- (4) Allow at least 1 µs setup.
- (5) While maintaining steps (2) and (3) above make R/W low, placing the device in servo write mode.

#### POWER SUPPLY FAULT PROTECTION

A voltage fault detection circuit improves data security by disabling the write current generator during a voltage fault or power startup regardless of mode.

#### **HEAD SHORT TO GROUND PROTECTION**

The SSI 32R2103R/04R/05R provide a head short to ground protection circuit in any mode. In idle or read mode, or for an unselected head in write mode, current out of the head port will not exceed 3 mA. If a selected head in write mode is shorted to ground, the write current generator will turn off, and remain off until the user exits write mode and then returns to write mode.

#### WRITE UNSAFE

Any of the following conditions will be indicated as a high level on the Write Unsafe, WUS, open collector output.

- · WDI frequency too low
- · Device in read mode
- · Device not selected
- · Device in servo write mode
- · No head current
- Open head
- Head short to ground
- · Power supply fault

#### WRITE UNSAFE (continued)

To prevent false WUS flags, the head inductance and resistance should be less than 1  $\mu H$  and 50 $\Omega$ , respectively.

WDI frequency too low is detected if the WDI frequency falls below 1 MHz (typ). Consult the WUS Safe to Unsafe timing for range of frequency detection.

Device in read mode, Device in servo write mode and Device not selected will flag WUS if  $R\overline{W}$  is high, if  $\overline{SE}$  is low, or  $\overline{CS}$  is high.

No head current will flag WUS if Rwc > 50 k $\Omega$ .

Head opened will flag WUS if Rh =  $\infty$ . To prevent false WUS flags, the open head detect is disabled when write data frequency is greater than 20 MHz.

**Head short to ground** is described in the preceding paragraph.

Upon entering write mode, WUS is valid within the specified R/W timing.

After the low frequency fault condition is removed, one positive transition of WD-WD (32R2103R/2105R), or one positive transition of WDX-WDY (32R2104R) is required to clear WUS

#### **READ MODE**

The read mode configures the SSI 32R2103R/04R/05R as a low noise differential amplifier and deactivates the write current generator. The damping resistor is switched out of the circuit allowing a high impedance input to the read amplifier. The RDX and RDY output are driven by emitter followers. They should be AC coupled to the load. The HnX, HnY inputs are non-inverting to the RDX, RDY outputs.

Note that in idle or write mode, the read amplifier is deactivated and RDX, RDY outputs become high impedance. This facilitates multiple R/W applications (wired-OR RDX, RDY) and minimizes voltage change when switching from write to read mode. Note also that the write current source is deactivated for both the read and idle mode.

In read mode, unselected heads are at ground potential.

#### **IDLE MODE**

Taking  $\overline{CS}$  high selects the idle mode which switches the RDX and RDY outputs into a high impedance state and deactivates the device. Power consumption in this mode is held to a minimum.

In idle mode, all heads are at ground potential.

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### PIN DESCRIPTION

#### CONTROL/STATUS

| NAME                  | TYPE | DESCRIPTION   |
|-----------------------|------|---|
| CS                    | Ī    | Chip Select Input. A logical low level enables the device.  |
| R/ <b>W</b> †         | ı    | Read/write. A logical high level enables read mode. A logical low level enables write mode.   |
| HS0, HS1, HS2,<br>HS3 | l    | Head Select. Decoded address selects one of 8 or 10 channels. See Table 2.  |
| WUS/SE†               | 0    | Write Unsafe/Servo Enable. When in servo bank write mode, pulling this pin above VCC enables servo bank write. See servo write mode section. Otherwise, a high level indicates an unsafe writing condition. See WUS section |
| WC†                   | i    | Write Current. Sets the write current through the recording head.   |

<sup>†</sup> when more than one read/ write device is used, signals can be wire OR'ed

### **HEAD TERMINAL CONNECTIONS**

| H0X-H9X | 1 | X,Y Head Connections |
|---------|---|----------------------|
| H0Y-H9Y |   |                      |

#### **DATA INPUT/OUTPUT**

| WD, WD†  | ı | Differential write data In. A positive transition of WD-WD changes the direction of current in the recording head. (32R2103R/2105R) |
|----------|---|---|
| WDX, WDY | I | Dirrerential write data In. Each transition of WDX-WDY changes the direction of current in the recording head. (32R2104R)           |
| RDX,RDY† | 0 | Differential read data out. Emitter follower output.  |

## **POWER**

| VCC | 5V power supply  |
|-----|------------------|
| VDD | 12V power supply |
| GND | Ground           |

## **ELECTRICAL SPECIFICATIONS**

Current maximums are currents with the highest absolute value.

### **ABSOLUTE MAXIMUM RATINGS**

Operation beyond the maximum ratings may damage the device.

| PARAMETER                      |         | RATING |                    |  |
|--------------------------------|---------|--------|--------------------|--|
| DC Supply Voltage              |         | VCC    | -0.3 to 6 Vdc      |  |
|                                |         | VDD    | -0.3 to 14.0 Vdc   |  |
| Write Current                  |         | tw     | 100 mA             |  |
| Digital Input Voltage          |         | Vin    | -0.3 to VCC + 0.3V |  |
| Head Port Voltage              |         | VH     | -0.3 to VDD + 0.3V |  |
| WUS Pin Voltage                | )       | Vwus   | -0.3 to VCC + 2V   |  |
| Output Current                 | RDX,RDY | lo     | -6 mA              |  |
| WUS                            |         | lwus   | 12 mA              |  |
| Junction Operating Temperature |         | Tj     | 125°               |  |
| Storage Tempera                | ature   |        | -65 to 150°        |  |

#### **RECOMMENDED OPERATING CONDITIONS**

| DC Supply Voltage             | VCC | 5 ± 10%V        |
|-------------------------------|-----|-----------------|
|                               | VDD | 12 ± 10%V       |
| Ambient Operating Temperature | Ta  | 0° < Ta < 75°   |
| Head Inductance               | Lh  | Lh < 1 μH       |
| Head Resistance, Valid WUS    | Rh  | $Rh < 50\Omega$ |

### **TEST CONDITIONS**

Recommended operating conditions apply.

| Write Current, Iw                                | 20 mA |
|--|-------|
| Head Inductance, Lh                              | 1 μΗ  |
| Head Resistance, Rh                              | 30Ω   |
| WD Frequency                                     | 5 MHz |
| WD, WD rise/fall time (32R2103R/2103/2105/2105R) | 1 ns  |
| WDI rise/fall time (32R2104/2104R)               | 1 ns  |

### **POWER DISSIPATION**

Recommended operating conditions apply.

| PARAMETER               | CONDITION          | MIN | NOM                      | MAX                      | UNIT |
|-------------------------|--------------------|-----|--------------------------|--------------------------|------|
| VCC Supply Current      | read mode          |     | 46                       | 60                       | mA   |
|                         | write mode         |     | 20                       | 22                       | mA   |
| VCC Supply              | SBW mode (4 heads) |     | 50                       | 65                       | mA   |
|                         | idle mode          |     | 0.6                      | 1                        | mA   |
| VDD Supply Current      | read mode          |     | 0.4                      | 0.7                      | mA   |
|                         | write mode         |     | lw + 7                   | lw + 10                  | mA   |
| VDD Supply              | SBW mode (4 heads) |     | 28 + 4 • lw              | 40 + 4 • lw              | mA   |
|                         | idle mode          |     | 0.3                      | 0.6                      | mA   |
| Power Dissipation       | read mode          |     | 235                      | 340                      | mW   |
|                         | write mode         |     | (184 mW)<br>+ (Iw x VDD) | (253 mW)<br>+ (tw x VDD) | mW   |
| Total Power Dissipation | SBW mode (4 heads) |     |                          | 886 + 4<br>• lw • VDD    | mW   |
|                         | idle mode          |     | 6.6                      | 13                       | mW   |

### **DIGITAL INPUTS**

| DIGITAL INI OTO                                   |     |                   |         |    |           |     |
|---|-----|-------------------|---------|----|-----------|-----|
| Input High Voltage<br>HSX, CS, R/W                | Vih |                   | 2       |    |           | VDC |
| Input Low Voltage<br>HSX, CS, R/W                 | Vil |                   |         |    | 0.8       | VDC |
| Input High Current<br>HSX, CS, R/W                | lih | Vih = 2V          |         |    | 100       | μА  |
| Input Low Current<br>HSX, CS, R/W                 | lil | Vil = 0.8V        | -400    |    |           | μА  |
| (WD/WD) and (WDX/WDY) Input High Voltage          | Vih |                   | 2       |    | Vcc - 0.2 | VDC |
| (WD/WD) and (WDX/WDY)<br>Input Low Voltage        | Vil |                   | Vih - 2 |    | Vih - 0.3 | VDC |
| (WD/WD) and (WDX/WDY)<br>Input Voltage Difference |     |                   | 0.3     |    | 2         | ٧   |
| (WD/WD) and (WDX/WDY) Input High Current          |     | Vih = Vcc - 0.75V |         | 85 | 110       | μА  |
| (WD/WD) and (WDX/WDY) Input Low Current           |     | Vih = Vcc - 1.75V |         | 70 | 100       | μА  |

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## **ELECTRICAL SPECIFICATIONS** (continued)

### **DIGITAL OUTPUTS**

| PARAMETER               |     | CONDITION      | MIN  | NOM | МАХ | UNIT |
|-------------------------|-----|----------------|------|-----|-----|------|
| WUS Output Low Voltage  | Vol | lol = 2 mA max |      |     | 0.5 | VDC  |
| WUS Output High Current | loh | Voh = Vcc      | -100 | 0   | 100 | μА   |

### WRITE CHARACTERISTICS

Test conditions apply unless otherwise specified.

| Write Current Range             | ,                                    | 10   |      | 35   | mA    |
|---------------------------------|--------------------------------------|------|------|------|-------|
| Write Current Voltage Vwc       |                                      |      | 2    |      | V     |
| Write Current Gain Awc          | lw = Aw•Vwc/Rwc                      |      | 20   |      | mA/mA |
| Write Current Constant "K"      | lw = K/Rwc                           | 36   | 40   | 44   | V     |
| Differential Head Voltage Swing | Open Head, Iw = 20 mA                | 11   | 13   | 1    | Vp-p  |
| Head Differential Rd            | 32R2103R/2104R                       | 200  | 250  | 300  | Ω     |
| Load Resistance                 | 32R2103/2104                         | 1000 | 1500 | 2000 | Ω     |
|                                 | 32R2105R                             | 400  | 500  | 600  | Ω     |
|                                 | 32R2105                              | 1000 | 1500 | 2000 | Ω     |
| WD Pulse Width                  | PWH                                  | 5    |      |      | ns    |
|                                 | PWL                                  | 5    |      |      | ns    |
| Unselected Head Voltage         |                                      |      |      | 0.1  | VDC   |
| Unselected Head Current         |                                      |      |      | 0.2  | mA    |
| VCC Fault Voltage               | lw ≤ 0.2 mA                          | 3.9  | 4.1  | 4.3  | ٧     |
| VDD Fault Voltage               | lw ≤ 0.2 mA                          | 8.5  | 9.3  | 10   | ٧     |
| Head Current HnX, HnY           | VCC, VDD low voltage fault condition | -0.2 |      | 0.2  | mA    |

## **SERVO WRITE CHARACTERISTICS**

| Write Current Range    |                          | 10 |         | 20      | mA |
|------------------------|--------------------------|----|---------|---------|----|
| Write Current Matching | Between channels         |    | ±10     |         | %  |
| WUS/SE Voltage         | Servo bank write enabled |    | VCC+1.5 | VCC+1.9 | V  |
| WUS/SE Sink Current    | Servo bank write enabled | 10 | İ       | 1       | mA |

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### **READ CHARACTERISTICS**

Test conditions apply unless otherwise specified. CL (RDX, RDY) < 20 pF, RL (RDX, RDY) = 1 k $\Omega$ .

| PARAMETER                              |       | CONDITION  | MIN  | NOM     | MAX  | UNIT   |
|--|-------|--|------|---------|------|--------|
| Differential Voltage Gain              |       | Vin = 1 mVp-p @1 MHz<br>32R2103RW/04RW   | 210  | 250     | 290  | V/V    |
| Voltage BW 32R2103R/04R                | -1 dB | $ Zs  < 5\Omega$ , Vin = 1 mVp-p   | 45   | Ì       |      | MHz    |
|  | -3 dB |  | 85   |         |      | MHz    |
| 32R2105R                               | -1 dB |  | 35   |         |      | MHz    |
|  | -3 dB |  | 75   |         |      | MHz    |
| Input Noise Voltage                    |       | BW = 20 MHz, Lh = 0, Rh = 0  |      | 0.45    | 0.63 | nV/√Hz |
| Input Noise Current                    |       | BW = 20 MHz, Lh = 0, Rh = 0  |      | 4       | 10   | pA/√Hz |
| Differential Input Capacitance         |       | Vin = 1 mVp-p, f = 5 MHz   |      | 10      | 14   | pF     |
| Differential Input Resistan            | ice   | Vin = 1 mVp-p, f = 5 MHz<br>32R2103/2104   | 450  | 750     | 1800 | Ω      |
|  |       | 32R2103R/2104R   | 450  | 750     | 1800 | Ω      |
| Dynamic Range                          |       | AC input voltage where gain falls to 90% of its small signal gain value, f = 5 MHz | 2    | 4       |      | mVp-p  |
| Common Mode Rejection                  | Ratio | Vin = 0 VDC + 100 mVp-p<br>@ 5 MHz   | 50   | 60      |      | dB     |
| Power Supply Rejection F               | Ratio | 100 mVp-p @ 5 MHz on VCC   | 50   | 70      |      | dB     |
| Channel Separation                     |       | Unselected channels driven with Vin = 0 VDC + 100 mVp-p                            | 50   | 60      |      | dB     |
| Output Offset Voltage AV = 250         |       | Lh = 0, Rh = 0   | -250 |         | 250  | mV     |
| Single Ended Output Resistance         |       | f = 5 MHz  |      | 30      |      | Ω      |
| Output Current Peak to Peak            |       | AC coupled load, RDX to RDY  | 3    | 5       |      | mA     |
| RDX, RDY Common Mode<br>Output Voltage |       |  |      | Vcc-2.2 |      | VDC    |

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## **ELECTRICAL SPECIFICATIONS** (continued)

### **SWITCHING CHARACTERISTICS**

Test conditions apply unless otherwise specified.

| PARAMI    | ETER                     | CONDITION   | MIN | NOM | MAX  | TINU |
|-----------|--------------------------|---|-----|-----|------|------|
| R/W       | read to write            | R/W to 90% of write current   |     |     | 0.15 | μs   |
|           | write to read            | R/W to 90% of<br>100 mV read signal envelope                                      |     |     | 0.20 | μs   |
| <u>CS</u> | Unselect to Select       | CS to 90% of 100 mV 10 MHz read signal envelope                                   |     |     | 0.20 | μs   |
| İ         | Select to Unselect       | CS to 10% of write current  |     |     | 0.15 | μs   |
| HS0,1, 2  | , 3 to any Head          | To 90% of 100 mV 10 MHz read signal envelope                                      |     |     | 0.15 | μs   |
| wus       | Safe to Unsafe (TD1)     | write mode, loss of WD<br>transitions; Defines max WD<br>period for WUS operation | 0.6 | 2   | 3.6  | μs   |
|           | Unsafe to Safe (TD2)     | Fault cleared: from first<br>WD transition  |     | 0.1 | 0.2  | μs   |
| WDI       | Frequency Range          | Valid WUS   | 1   |     | 100  | MHz  |
| Head Cu   | rrent                    | Lh = 0, Rh = 0  |     |     |      |      |
| V         | VD - WD to lx - ly (TD3) | 50% to 50%  |     | 3   | 5    | ns   |
| WD        | X - WDY to Ix - Iy (TD3) | 50% to 50%  |     | 3   | 5    | ns   |
|           | Asymmetry                | WD has 1 ns rise/fall time  |     |     | 0.5  | ns   |
|           | Rise/fall Time           | 10% to 90% points<br>lw = 20 mA, Rh = 0, Lh = 0                                   |     |     | 3    | ns   |
|           |                          | lw = 20 mA, Rh = 20Ω, Lh = 600 nH   |     |     | 7    | ns   |

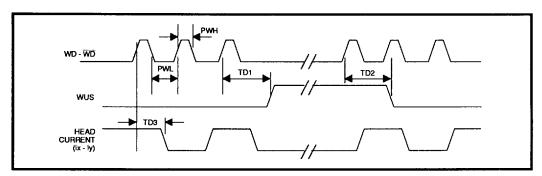


FIGURE 1: Write Mode Timing Diagram (32R2103R)

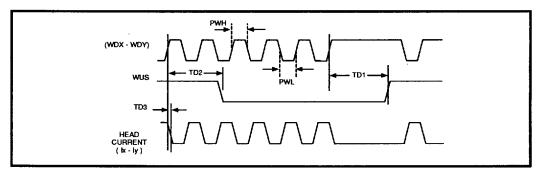
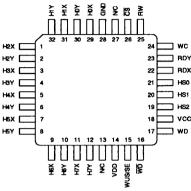


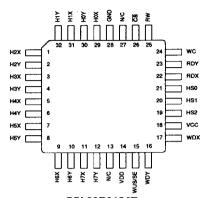
FIGURE 2: Write Mode Timing Diagram (32R2104R)

## PACKAGE PIN DESIGNATIONS

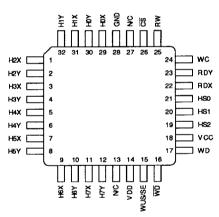
(Top View)



SSI 32R2103R 32-Lead, PECL Write Data Input 8-Channel TQFP



SSI 32R2104R 32-Lead, TTL Input Without Flip-Flop 8-Channel TQFP



SSI 32R2105R 32-Lead, PECL Write Data Input 8-Channel TOFP

CAUTION: Use handling procedures necessary for a static sensitive component.

Advance Information: Indicates a product still in the design cycle, and any specifications are based on design goals only. Do not use for final design.

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